VS-20L15TPbF, VS-20L15T-N3

Vishay Semiconductors



TO-220AC Base cathode 0 2 0 2 0 1 0 3 Cathode Anode

PRODUCT SUMMARY								
Package	TO-220AC							
I _{F(AV)}	20 A							
V _R	15 V							
V _F at I _F	See Electrical table							
I _{RM} max.	600 mA at 100 °C							
T _J max.	125 °C							
Diode variation	Single die							
E _{AS}	10 mJ							

Schottky Rectifier, 20 A

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Single diode configuration
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



- RoHS COMPLIANT HALOGEN FREE
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	A						
V _{RRM}		15	V						
I _{FSM}	t _p = 5 μs sine	700	A						
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V						
TJ	Range	- 55 to 125	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20L15TPbF	VS-20L15T-N3	UNITS				
Maximum DC reverse voltage	V _R	15	V					
Maximum working peak reverse voltage	V _{RWM}	15	15	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 85$ °C,	20						
Maximum peak one cycle non-repetitive surge current	Irou	5 μs sine or 3 μs rect. pulse Following any rated lo condition and with ra		700	А				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	330					
Non-repetitive avalanche energy	E _{AS}	T_J = 25 °C, I_{AS} = 2 A, L = 6 mH	10	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	2	А					

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		SPEC	

PARAMETER	ST CONDITIONS	TYP.	MAX.	UNITS		
		19 A	T.I = 25 °C	-	0.41	
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 C	-	0.52	v
See fig. 1	VFM ()	19 A	T_I = 125 °C	0.25	0.33	
		40 A	IJ = 125 C	0.37	0.50	
Reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C		-	10	mA
See fig. 2	IRM (")	T _J = 100 °C	V _R = Rated V _R	-	600	
Threshold voltage	V _{F(TO)}	0.182		182	V	
Forward slope resistance	r _t	$T_J = T_J max.$		7.6		mΩ
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$, (test sig	nal range 100 kHz to 1 MHz) 25 °C	-	2000	pF
Typical series inductance	L _S	Measured lead to lead	8	-	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000		V/µs	

Note

Г

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		- 55 to 125	0°				
Maximum storage temperature range	T _{Stg}		- 50 to 150					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W				
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40					
Approvimeto weight			2	g				
Approximate weight			0.07	oz.				
Mounting torque		Non lubricated threads	6 (5)	kgf · cm (lbf · in)				
Mounting torque maximum		Non-lubricated threads	12 (10)					
Marking device		Case style TO-220AC	20L1	5T				



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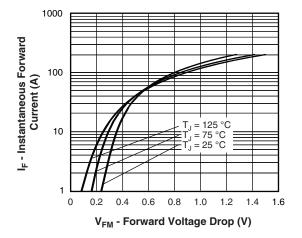
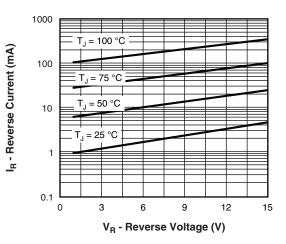
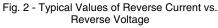


Fig. 1 - Maximum Forward Voltage Drop Characteristics





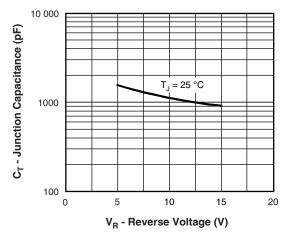
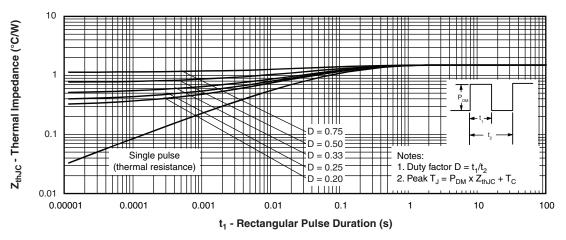
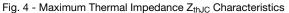
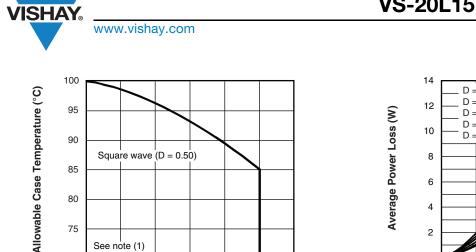


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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12 I_{F(AV)} - Average Forward Current (A)

16

20

24

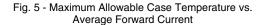
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See note (1)

4

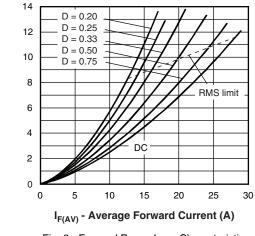
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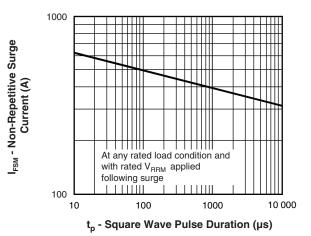


Fig. 7 - Maximum Non-Repetitive Surge Current

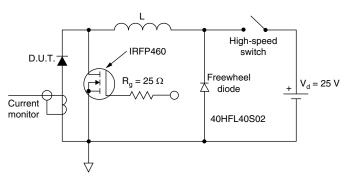


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6);

 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; $I_R \text{ at } V_{R1}$ = 80 % rated V_R

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4

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ORDERING INFORMATION TABLE

Device code	VS-	20	L	15	т	PbF	
	1	2	3	4	5	6	
	1 2 3 4 5	- Cur - Sch - Volt - Pac	rent rati ottky "L age coo kage	niconduo ng (20 = " series de (15 =	20 A)	oduct	
	6	- Env • F	bF = Le	ntal digit ead (Pb)	-free an		compliant
		• -	N3 = Ha	liogen-fr	ee, Ror	15 comp	pliant, and totally lea

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-20L15TPbF	50	1000	Antistatic plastic tube					
VS-20L15T-N3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224				
	TO-220AC -N3	www.vishay.com/doc?95068				



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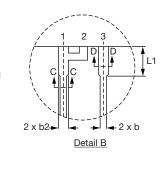
TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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